Field-tuned quantum tunneling in a supram olecule dim er [M n₄]₂

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A bstract

Field-tuned quantum tunneling in two single-molecule magnets coupled antiferrom agnetically

and formed a supram olecule dimer is studied. We obtain step-like magnetization curves by

m eans of the num erically exact solution of the time-dependent Schrödinger equation. The steps

in magnetization curves show the phenomenon of quantum resonant tunneling quantitatively.

The e ects of the sweeping rate of applied eld is discussed. These results obtained from

quantum dynamical evolution well agree with the recent experiment W W emsdorfer et al. Nature

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Them acroscopic quantum phenomena in molecular magnets has become a very attractive researching eld. Many properties of these nanometer-sized magnetic particles and clusters, such as M n_{12} (s = 10), Fe $_8$ (s = 10) and M n_4 (s = $\frac{9}{2}$) systems, have been well studied [1] [6] both experimentally and theoretically. Theoretically, studying the phenomenon of quantum resonant tunneling of these molecular magnets could be based on Landau-Zener (LZ) transitions [7]; [8], or based on numerically the solution of the time-dependent Schrodinger equation [9]; [10]. In Landau-Zener model, the magnetization curves could be obtained in a static and approximate way. Recently a supermolecular dimer [M n_4] is reported to be synthesized successfully by Wemdorfer et al. [11]. In this kind of supermolecular dimer, two single-molecule magnets M n_4 antiferrom agnetic coupled each other, which results in its quantum behavior quite dimernt from two individual M n_4 molecule without coupling. In this paper, we calculate magnetization curves of a supermolecular dimer [M n_4] a single-molecule magnets, by numerically exact solution of the time-dependent Schrodinger equation.

Following W emsdorfer et al., the model H am iltonian of the supermolecular dim er M n_4 \geq is

$$H = H_1 + H_2 + JS_1$$
 \$; (1)

where J is the weak antiferrom agnetic supercharging coupling constant. H_1 and H_2 are H am iltonian for two individual M n_4 m olecules in the superm olecular dimer. It is known that the model H am iltonian of an individual M n_4 molecule is

$$H_{i} = D S_{zi}^{2} + E (S_{xi}^{2} S_{yi}^{2}) \quad g_{B} S_{zi} h_{z} (t); i = 1; 2;$$
 (2)

where D and E are the axial anisotropic constants. h_z (t) is the applied sweeping eld along easy axis. We can easily obtain the energy eigenvalues of whole Ham iltonian H (Figure 1). In experim ent the sweeping rate of h_z (t) is very slow, so we can simulate it as a step-increased eld, which means the h_z increases a value h_z every time step and keeps constant during the time intervals. Note that we can not use a sweeping rate as slow as experiment due to the limitation of our computing time. However, we can obtain the key macroscopic quantum phenomena in our calculation with relatively high sweeping rate. In this paper, we select D = 0.72k; J = 0.1k; $I^{[1]}$ and $E = 0.0317k^{[6]}$. Dynamic evolution follows time-dependent schrydinger equation and can be calculated by

$$j(t)i = j(t_0 + n)i = \exp[iH(t_0 + (n 1))]j(t_0 + (n 1))i;$$
 (3)

Meanwhile, j (t) i can be expanded as

$$j (t)i = \begin{cases} X^{S} & X^{S} \\ a_{m_{1} = Sm_{2} = S} \end{cases} a_{m_{1}, m_{2}} (t) j_{m_{1}}; m_{2}i; S = \frac{9}{2};$$
(4)

where $j_{1}m_{2}i$ are the eigenstates of H $_{0}$ that is

$$H_0 = D S_{z1}^2 D S_{z1}^2 + J S_{z1} S_{z2} g_B (S_{z1} + S_{z2}) h_z (t);$$
 (5)

We assume the initial states to be at $\frac{9}{2}$; $\frac{9}{2}$, and the whole evolution process can be obtained by equation (4) step by step. In Ref.^[11], We emsdorfer report ve points (Figure 4 of Ref.) of resonant tunneling that result in the steps in hysteresis loops. They considered the rst point is caused by the resonant transition from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{9}{2}$, and the fourth point is caused by those from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{9}{2}$. However, under the model Hamiltonian of Equation (1) and Equation (2), the transitions of these points are quenched for a half integer spin due to the parity symmetry $^{[12];[13]}$. Therefore, there must be somekind of transverse eld components resulted from the in unce of the environmental degrees of, such as hyper neand dipolar couplings, and it can be approximated a Gaussian distribution with a width = 0.035T for such additional transverse environmental eld. In this paper, we simply assume it to be a constant and $h_x = 0.01T$ along x axis, but do not lose the essential physics, the macroscopic quantum phenomena.

The magnetization along the z axis can be simply defined by M = $\langle S_{z1} + S_{z2} \rangle$. In Figure 2, we plot the magnetization curve responding to a time-dependent applied eld with a constant transverse eld $h_x = 0.01T$. There are three steps in the magnetization curve. In order to know the details of state transitions, the states (j (t)i) near to two sides of resonant points are recorded in our simulation and they are shown in Table 1, where the occupied probabilities $(j_{a_{m_1,m_2}}(t)_j^2)$ are neglected to zeros if they less than 10^3 . Therefore, we can get clear inform ation of the process of evolution and transition. Figure 1 and Table 1 show that the first step occurs at $h_z = 0.198T$ from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{7}{2}$ (and $\frac{7}{2}$; $\frac{9}{2}$), and the second step occurs at $h_z = 0.731T$ from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{7}{2}$ (and $\frac{5}{2}$; $\frac{9}{2}$). These two resonant points the twell to experimental results (i.e. the point 2 and the point 4 of Fig.4 in Ref. 11). The third step occurs at $h_z = 0.812T$ from $\frac{9}{2}$; $\frac{5}{2}$ (and $\frac{5}{2}$; $\frac{9}{2}$) to $\frac{7}{2}$; $\frac{5}{2}$ (or $\frac{5}{2}$; $\frac{7}{2}$). There is no step at $h_z = 0.33T$ in our magnetization curve, but the experiment reports a point of resonant tunneling (the point 1 in Fig.4 of Ref. 11). The reason is that we have used a too fast sweep rate in our simulation. We will interpret it more detail late. In our

m agnetization curve, since the step at $h_z = 0.33T$ from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{9}{2}$ does not occur, therefore the step at $h_z = 0.87T$ from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{7}{2}$; $\frac{9}{2}$ (point 4 in the Fig.4 of Ref. [11]) can not occur naturally.

In order to interpret why there is no step at $h_z=0.33T$ in our magnetization curve, we rstly consider a utmost-slow process. At any t value, the eigenstates and eigenvalues (Figure 1) of whole Hamiltonian H (t) can be calculated by

$$H (t) j (E) i = E j (E) i;$$
 (6)

Note that no matter how weak it is, the system always interact with environment which cause dissipation. Therefore, in a very very slow process, we can assume that the state j (t) i of system evaluating from a initial state j (0) i will always relax to the ground state j (E $_{\rm min}$)i of H (t). Figure 3 shows the magnetization curve of this utmost-slow process. There are two steps at hz 0:3363T and h_z 0:3363T in the curve. It means that the 0.3363T (point 1 of Fig.4 of Ref.^[11]) occurs when point of resonant tunneling at hz the sweeping rate of applied eld is very slow. In gure 2, the sweeping rate of applied eld in our calculation is c = $\frac{h_z}{10^{-8}} = \frac{10^{-5}}{10^{-8}} = 1000$ T esla=s, which is much more larger than the ones in experiment (0:140 Tesla=s, 0:035 Tesla=s and 0:004Tesla=s)[11]. Due to the limitation of our computer time, we can not do the calculation for a sweeping rate of applied eld as slow as the one in experiment. We now try to simulate the magnetization process (Figure 4) only in a very sharp range of h_z with sweeping rates as slow as the ones used in experiment. In our gure 4, (a) is calculated over a range of $h_{\rm z}$ from $0.3362 \text{ Tesla with parameters} = 10^8 \text{ s}$ and $h_z = 10^9 \text{ Tesla}$ (the sweeping rate 0.10Tesla=s); (b) is calculated over a range of h_z from 0:336295 Tesla to 0:336275 Tesla with parameters = 10^8 s and h $_z$ = 10^{10} Tesla (the sweeping rate 0.01Tesla=s); (c) is the combination of (a) and (b). A very clear step occurs at h_z 0.336283T point, and it shows that the slower sweeping rate induces the higher step occurred. The recorded states (Table 2) at transition point h_z 0:3363 Tesla show that the resonant tunneling is from $\frac{9}{2}$; $\frac{9}{2}$ to $\frac{9}{2}$; $\frac{9}{2}$ (and $\frac{9}{2}$; $\frac{9}{2}$). All these results twellwith the results of experiment [11]. Therefore, it clear show that the reason for no step at point about hz from too fast sweeping rate of the applied eld in theoretical simulation. There are some sm all oscillations in the magnetization curve. It is caused from quantum uctuations.

In conclusion, We have studied the phenomenon of quantum resonant tunneling in a

superm olecular dim er $M n_4 \ b$ of single-molecule magnets by numerically exact solution of the time-dependent Schrödinger equation. We obtain step-like magnetization curves which demonstrate quantum tunneling quantitatively. We have calculated and discussed the alect to steps caused by different sweeping rate of applied led. It shows that some steps can not occur at some resonant points when the sweeping rate is too fast, but they could appear when the sweeping rate becomes enough slow. At a very narrow region near resonant point, we slow down the sweeping rate of applied led, some quantum resonant tunnelling appeared in experiment can appear. Meanwhile, theoretical calculation show that more slow rate induces more higher transition step. The results of our calculation is twenty well with the experiment. Note that since we do not take into account the elects of dissipation caused by environment, the magnetization curves we obtain can not reach a reversal saturation value even if the applied led increase to in nitive value. Therefore, if we want to calculate a whole hysteresis loop, a proper mechanism of dissipation should be taken into account.

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caption

Table1: Occupied probabilities j_{m_1,m_2} (t) j^2 at spin states j_{m_1} ; m_2 i (Equation (5)) at some points of the evolution process (Figure 2). The values are neglected to zero if they are

sm aller than 0:001.

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h _z (Tesla)	-0.34	-0.32	0.19	0.21	0.72	0.74	0.80	0.82	0.9
$\frac{9}{2}$, $\frac{9}{2}$	0.9986	0.9987	0.9987	0.9861	0.9855	0.9719	0.9718	0.9718	0.9717
$\frac{9}{2}$, $\frac{7}{2}$	0	0	0	0.0062	0.0061	0.0060	0.0062	0.0061	0.0060
$\frac{7}{2}$; $\frac{9}{2}$	0	0	0	0.0062	0.0061	0.0060	0.0062	0.0061	0.0060
9 ; 5 2 ; 2	0	0	0	0	0	0.0068	0.0067	0.0053	0.0053
$\frac{5}{2}$; $\frac{9}{2}$	0	0	0	0	0	0.0068	0.0067	0.0053	0.0053
$\frac{7}{2}$; $\frac{5}{2}$	0	0	0	0	0	0	0	0.0013	0.0013
$\frac{5}{2}$; $\frac{7}{2}$	0	0	0	0	0	0	0	0.0013	0.0013
T otal	0.9986	0.9987	0.9987	0.9985	0.9977	0.9975	0.9977	0.9973	0.9970

Table2: O ccupied probabilities j_{2m_1,m_2} (t) j_2^2 at spin states j_{m_1},m_2 i (Equation (5)) at some points of the evolution process (Figure 4). The values are neglected to zero if they are

sm aller than 0:0001.

Figure 4	(á	a)	(b)		
h _z (Tesla)	-0.3364	-0.3362	-0.336295	-0.336275	
$\frac{9}{2}$; $\frac{9}{2}$	1	0.9966	1	0.9679	
$\frac{9}{2}$; $\frac{9}{2}$	0	0.0016	0	0.0160	
$\frac{9}{2}$; $\frac{9}{2}$	0	0.0016	0	0.0160	
T otal	1	0.9998	1	0.9999	

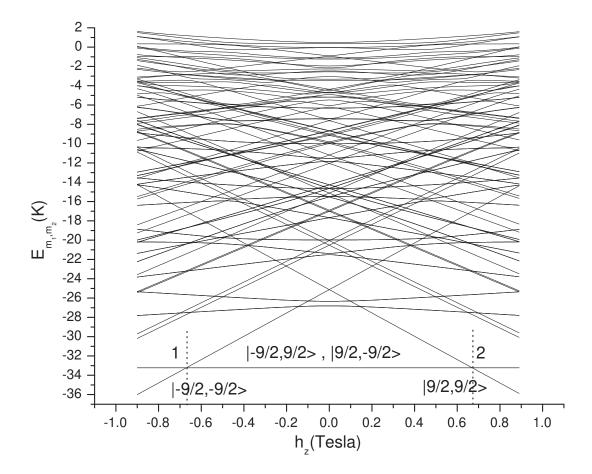


FIG. 1: The 100 spin state energies of the model H am iltonian (Equation (1)) as a function of longitude applied eld. A weak transverse eld $h_{\rm x}=0.01T\,{\rm esla}$ is take into account.

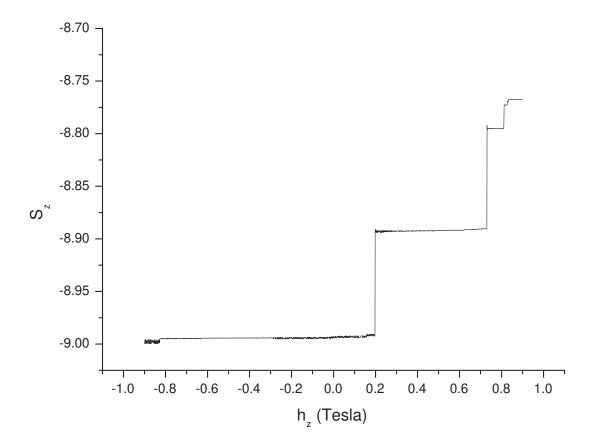


FIG .2: M agnetization relaxation of ground state (M agnetization curve reponse to a sweeping eld. The sweeping rate is $c=\frac{h_z}{10^{-8}}=\frac{10^{-5}}{10^{-8}}=1000T$ esla=s.

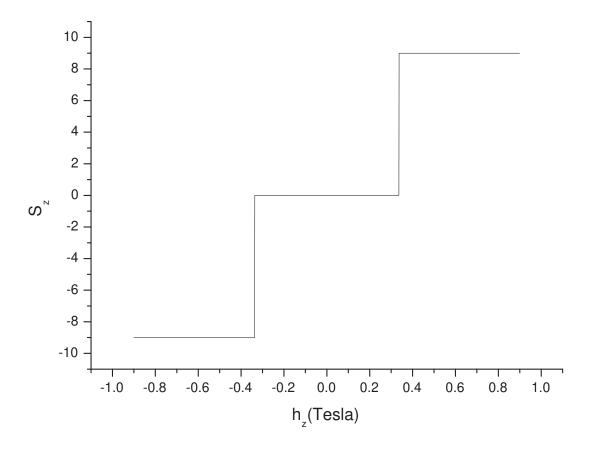


FIG. 3: M agnetization curve based on a utm ost-slow process. It suppose that the state j (t)i of system always relax to the ground state j (E $_{\text{m in}}$)i of H (t).

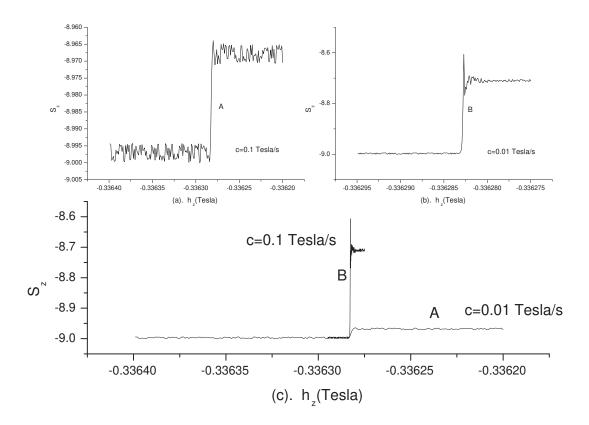


FIG. 4: M agnetization curves response to slow sweeping elds over very sharp ranges of h_z . The sweeping rates are the same order with that used in experiment (Ref. [1]).